PCN Number: 20181011000.1							<b>PCN</b>	Date:	Oct 15, 201	
I ITIA'	ualification IPA07 Techr		B as an ad	ditiona	al Wafer Fab S	Site op	tion 1	for sele		
Customer Contact:			PCN Manager Dept:			Dept:	Quality Services			
Droposed 1	it Shin Date	1:	an 15, 2019	٥	Estimated S	Sampl	е	Dat	e provided at	
Proposed 1 <sup>st</sup> Ship Date:			all 15, 201	9	Availability:			san	sample request.	
Change Typ	e:									
Assemb	y Site		Assembly Process					Assembly Materials		
Design					cification		ш		Mechanical Specificatio	
Test Site			_		oing/Labeling		Щ	Test P		
	ump Site				Material		$\sqcup$		Bump Process	
⊠   Wafer Fa	ab Site							Wafer	Fab Process	
			Part nu							
				PCN	<u>Details</u>					
Description					1.6 6	5			<b>C</b>	
									on facility as a	
additional Wa	arer Fab sou	rce for	the selecte	ea aev	ices listed in	"Produ	ICT AF	rectea"	section.	
	Curren	t Sites	<b>.</b>			Addit	tiona	I Sites		
Current Process			Wafer Additional		Р	Process Wafer		Wafer		
Fab Site			Diame	ter	Fab Site				Diameter	
DP1DM5	HPA	07	200mm		RFAB		HPA07		200	
AIZU	HPA	07	200mm						300mm	
Qual details		in the	Qual Data	Section	on.					
Reason for	Change:									
Continuity of	Supply									
Anticipated	impact on	Form,	Fit, Funct	tion, (	Quality or Re	eliabil	ity (r	ositiv	e / negative	
None	-		·		-					
Changes to	product id	entific	ation resu	ıltina	from this PC	CN:				
	product id			9						
Current										
Chip Site	Chip	Site Or	Origin (20L) Cl		p Site Country Code (21L		Chi	Chip Site City		
DP1DM5	DM5		- , , ,		SA			Dallas		
AIZU	CU2		JPN					Aizuwakamatsu-shi		
, 1220	552			_ J•				171120	a.kamacoa o	
Now Eak S	+0									
New Fab S		Site Or	igin (201)	Chin	Site Country	Code	(211)	Chi	n Site City	
New Fab S Chip Site RFAB		Site Or	igin (20L)	Chip	Site Country	Code	(21L)		o Site City	

Sample product shipping label (not actual product label)



MSL 1 /235C/UNLIM 03/29/04 OPT: ITEM: 39

EL: 5A (L)T0:1750



(1P) \$N74L\$07N\$R (Q) 2000 (D) 0336 (31T) LOT: 3959047MLA (4W) TKY(1T) 7523483\$I2 (P) (P) (2DL) CSO: SHE (23L) ASO: MLA (23L) ACO: MYS

## **Product Affected Group:**

DRV401AIDWP	DRV401AIDWPRG4	DRV401AIRGWT	DRV401AIRGWTG4
DRV401AIDWPR	DRV401AIRGWR		

## **Qualification Report** RFAB G4DRV401GAP offload from Aizu DRV401AIRGWR Approve Date 28-Sept-2018

**Product Attributes** 

Attributes	Qual Device: DRV401AIRGWR	Process QBS Device: CD3232A1YFFR	Package QBS Device: DRV401AIRGWR	Package QBS Device: BQ24196RGER
Wafer Fab Supplier	RFAB	RFAB	Aizu	RFAB
Wafer Process	HPA07	HPA07	HPA07	LBC7
Assembly Site	CDAT	JCAP	CDAT	CDAT
Package Type	VQFN	WCSP	VQFN	WSON
Package Designator	RGW	YFF	RGW	DRV

<sup>-</sup> Qual Devices qualified at LEVEL2-260CG: DRV401AIRGWR

## Qualification Results

Data Displayed as: Number of lots / Total sample size / Total failed

			Qual Device:	Process QBS Device:	Package QBS Device:	Package QBS Device:
Type	Test Name / Condition	Duration	DRV401AIRGWR	CD3232A1YFFR	DRV401AIRGWR	BQ24196RGER
HAST	Biased HAST, 130C/85%RH	96 Hours	-	3/231/0	-	3/231/0
UHAST	Unbiased HAST 130C/85%RH	96 Hours	-	3/231/0	-	-
AC	Autoclave 121C	96 Hours	-	-	3/231/0	3/231/0
TC	Temperature Cycle, -65/150C	500 Cycles	-	3/231/0	3/231/0	-
HTSL	High Temp. Storage Bake, 170C	420 Hours	-	3/231/0	3/231/0	-
HTOL	Life Test, 125C	1000 Hours	2/154/0	3/231/0	-	-
ELFR	Early Life Failure Rate, 150C	24 Hours	-	3/2400/0	-	-
HBM	ESD - HBM	1500 V	1/3/0	3/9/0	-	-
нвм	ESD - HBM	1000 V	1/3/0	-		
CDM	ESD - CDM	1000 V	1/3/0	3/9/0	-	
LU	Latch-up	(Per AEC Q100-004)	1/6/0	3/18/0	-	-
ED	Electrical Distributions	Cpk>1.67 Room, Hot, & Cold Test	1/30/0	3/90/0	-	-
MQ	Manufacturability (Assembly)	(per mfg. Site specification)	Pass	Pass	-	-
MQ	Manufacturability (Wafer Fab)	(per mfg. Site specification)	Pass	Pass	-	-

<sup>-</sup> Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable

Quality and Environmental data is available at TI's external Web site: http://www.ti.com/

Green/Pb-free Status: Qualified Pb-Free(SMT) and Green

For questions regarding this notice, e-mails can be sent to the regional contacts shown below, or you can contact your local Field Sales Representative.

Location	E-Mail
USA	PCNAmericasContact@list.ti.com
Europe	PCNEuropeContact@list.ti.com
Asia Pacific	PCNAsiaContact@list.ti.com
Japan	PCNJapanContact@list.ti.com

<sup>-</sup> The following are equivalent HTOL options based on an activation energy of 0.7eV: 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours

<sup>-</sup> The following are equivalent HTSL options based on an activation energy of 0.7eV: 150C/1k Hours, and 170C/420 Hours

<sup>-</sup> The following are equivalent Temp Cycle options per JESD47: -55C/125C/700 Cycles and -65C/150C/500 Cycles